

600V 30A Field Stop Trench IGBT

V_{CES}	600V
I _{C(100°C)}	30A
V _{CE(sat) (Typ.)}	1.4V
P_D	111W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) Soft Switching
- 3) Pb free Lead Plating; RoHS Compliant

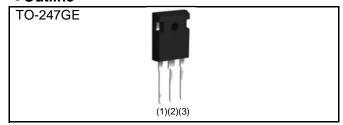
Applications

Partial Switching PFC

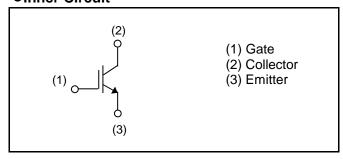
Discharge Circuit

Brake for Inverter

Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Type	Tape Width (mm)	-
Type	Basic Ordering Unit (pcs)	600
	Taping Code	C13
	Marking	RGCL60TS60

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V_{CES}	600	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	48	А
	T _C = 100°C	I _C	30	А
Pulsed Collector Current		I _{CP} *1	120	А
Power Dissipation	T _C = 25°C	P_D	111	W
	T _C = 100°C	P_D	55	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{imax.}

●Thermal Resistance

Parameter	Symbol	Values			Unit
Farameter		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	1.34	°C/W

ullet IGBT Electrical Characteristics (at $T_j = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
- Farameter	Symbol		Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_C = 10 \mu A, V_{GE} = 0 V$	600	1	1	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 600V, V_{GE} = 0V$	1	1	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V, V_{CE} = 0V$	-	-	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 18.9 mA$	4.5	5.5	6.5	V
Collector - Emitter Saturation Voltage		$I_C = 30A, V_{GE} = 15V$				
	V _{CE(sat)}	T _j = 25°C	-	1.4	1.8	V
		T _j = 175°C	-	1.6	-	

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Davamatav	Cymah al	Conditions	Values			Linit
Parameter	Parameter Symbol Conditions		Min.	Тур.	Max.	Unit
Input Capacitance	C_{ies}	V _{CE} = 30V	-	1600	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$	-	38	-	pF
Reverse Transfer Capacitance	C_{res}	f = 1MHz	-	29	-	
Total Gate Charge	Q_g	V _{CE} = 300V	-	68	-	
Gate - Emitter Charge	Q_{ge}	I _C = 30A	-	13	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	27	-	
Turn - on Delay Time	t _{d(on)}	$I_C = 30A, V_{CC} = 400V$	-	44	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	27	-	
Turn - off Delay Time	t _{d(off)}	T _j = 25°C	-	186	-	ns
Fall Time	t _f	Inductive Load	-	178	-	
Turn - on Switching Loss	E _{on}	*Eon includes diode	-	0.77	-	
Turn - off Switching Loss	E _{off}	reverse recovery	-	1.11	-	mJ
Turn - on Delay Time	t _{d(on)}	$I_C = 30A, V_{CC} = 400V$	-	40	-	
Rise Time	t _r	$V_{GE} = 15V, R_G = 10\Omega$	-	45	-	20
Turn - off Delay Time	t _{d(off)}	T _j = 175°C	-	207	-	ns
Fall Time	t _f	Inductive Load	-	272	-	
Turn - on Switching Loss	E _{on}	*Eon includes diode	-	0.97	-	m l
Turn - off Switching Loss	E_{off}	reverse recovery	-	1.54	-	mJ
		I _C = 120A, V _{CC} = 480V				
Reverse Bias Safe Operating Area	RBSOA	$V_P = 600V, V_{GE} = 15V$	FULL SQUARE			-
		$R_G = 60\Omega, T_j = 175^{\circ}C$				

• Electrical Characteristic Curves

Fig.1 Power Dissipation vs. Case Temperature

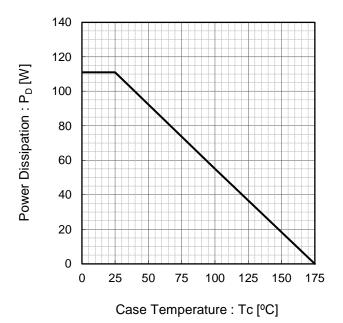


Fig.2 Collector Current vs. Case Temperature

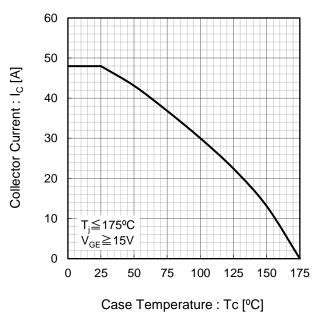


Fig.3 Forward Bias Safe Operating Area

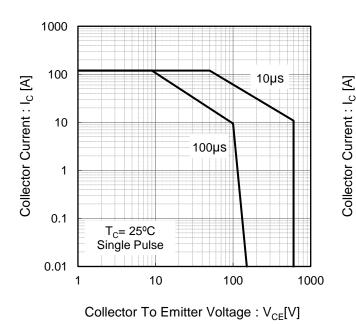
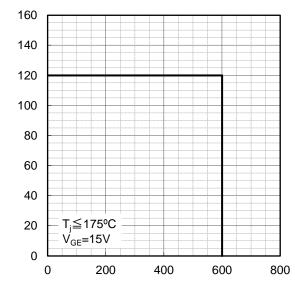


Fig.4 Reverse Bias Safe Operating Area



Collector To Emitter Voltage : $V_{CE}[V]$

Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

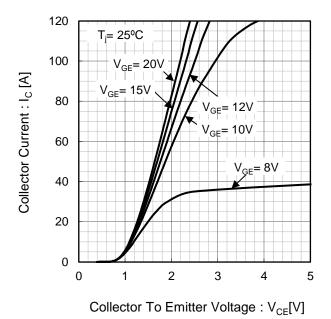
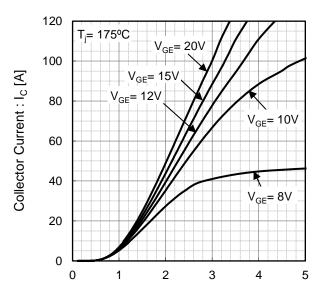


Fig.6 Typical Output Characteristics



Collector To Emitter Voltage : V_{CE}[V]

Fig.7 Typical Transfer Characteristics

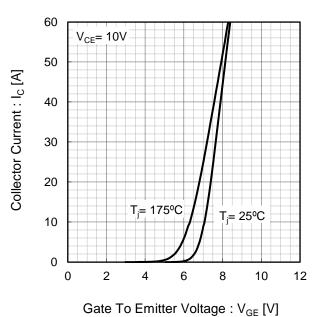
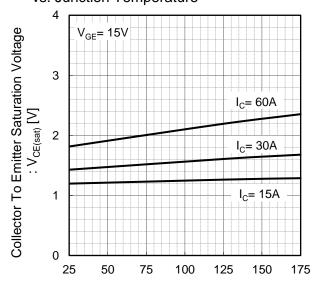


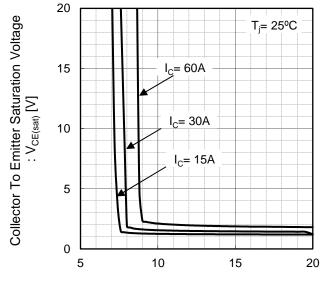
Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature



Junction Temperature : T_i [°C]

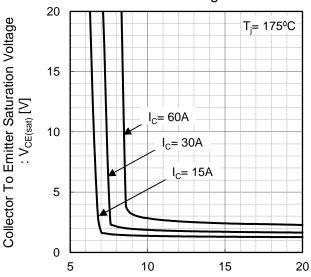
Electrical Characteristic Curves

Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



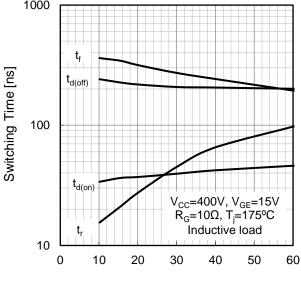
Gate To Emitter Voltage : V_{GE} [V]

Fig.10 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



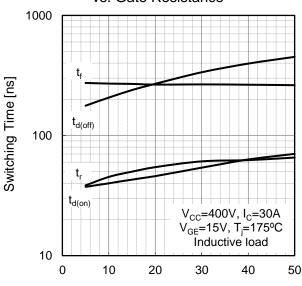
Gate To Emitter Voltage : V_{GE} [V]

Fig.11 Typical Switching Time vs. Collector Current



Collector Current : I_C [A]

Fig.12 Typical Switching Time vs. Gate Resistance



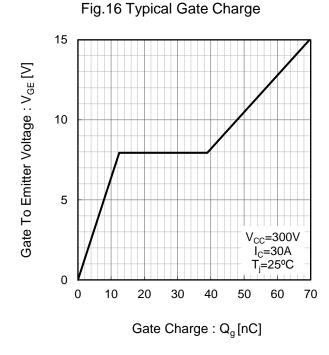
Gate Resistance : $R_G[\Omega]$

• Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs. Collector Current 10 Switching Energy Losses [mJ] 1 E_{on} 0.1 V_{CC} =400V, V_{GE} =15V R_G=10 Ω , T_j=175°C Inductive load 0.01 0 10 20 30 40 50 60 Collector Current : I_C [A]

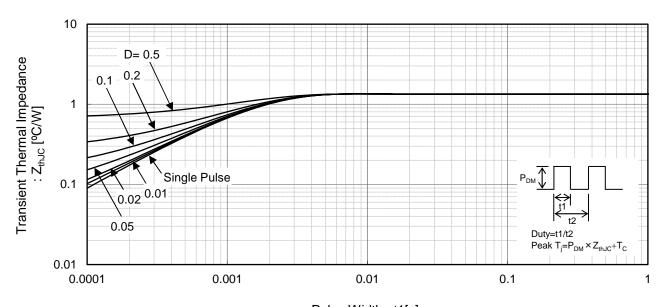
Fig.14 Typical Switching Energy Losses

Fig.15 Typical Capacitance vs. Collector To Emitter Voltage 10000 Cies 1000 Capacitance [pF] 100 Coes Cres 10 f=1MHz $V_{GE}=0V$ T_i=25°C 0.01 0.1 1 10 100 Collector To Emitter Voltage : V_{CE}[V]



• Electrical Characteristic Curves

Fig.17 IGBT Transient Thermal Impedance



Pulse Width: t1[s]

●Inductive Load Switching Circuit and Waveform

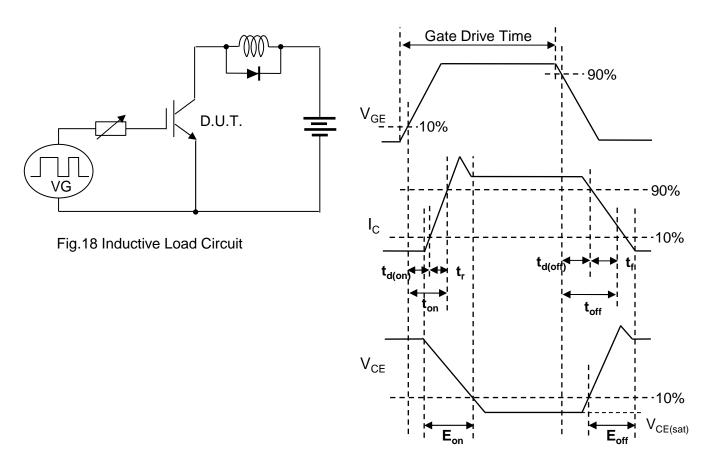


Fig.19 Inductive Load Waveform

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